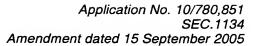
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AMENDMENT TRANSMITTAL LETTER (Large Entity) Applicant(s): Chan-Hyung CHO et al.					Docket No. SEC.1134		
Application No. 10/780,851	Filing Date 19 February 2004	Examiner WOJCIECHOWICZ, E. J.		Customer N 20987	No.	Group Art Unit 2815	Confirmation No. 2476
METHOD OF ENLARGING CONTACT AREA OF A GATE ELECTRODE, SEMICONDUCTOR DEVICE HAVING A SURFACE-ENLARGED GATE ELECTRODE, AND METHOD OF MANUFACTURING THE							
COMMISSIONER FOR PATENTS:							
Transmitted herew		n the above-identified a mitted as shown below	•	on.			<u> </u>
CLAIMS AS AMENDED							
	CLAIMS REMAINING	HIGHEST #	NUMBI	ER EXTRA		RATE	ADDITIONAL
	AFTER AMENDMENT	PREV. PAID FOR	CLAIMS	PRESENT			FEE
TOTAL CLAIMS	38 -	38 =	ļ	0	x	\$50.00	\$0.00
INDEP. CLAIMS	2 -	3 =		0	x	\$200.00	\$0.00
Multiple Dependent Claims (check if applicable)							\$0.00
TOTAL ADDITIONAL FEE FOR THIS AMENDMENT \$0.00							
 No additional fee is required for amendment. □ Please charge Deposit Account No. in the amount of □ A check in the amount of to cover the filing fee is enclosed. ☑ The Director is hereby authorized to charge payment of the following fees associated with this communication or credit any overpryment to Deposit Account 50-0238 ☑ Any additional filing fees required under 37 C.F.R. 1.16. ☑ Any patent application processing fees under 37 CFR 1.17. □ Payment by credit card. Form PTO-2038. WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038. 							
KENNETH D. SP. Reg. No. 39,843 Volentine Francos One Freedom Squ 11951 Freedom Dr. Reston, VA 20190 Tel. No. 571-283-0	s & Whitt, P.L.L.C. nare rive, Suite 1260		the Ur	by certify that nited States Po nail in an enve	this ostal	correspondence Service with suf addressed to "Co	is being deposited with fficient postage as first mmissioner for Patents, " [37 CFR 1.8(a)] on
Signature of Person Mailing Corresponden							respondence

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

:

In re PATENT APPLICATION of

Chan-Hyung CHO et al.

Art Group Unit 2815

Application No. 10/780,851

Examiner: E. J. WOJCIECHOWICZ

Filing Date: February 19, 2004

Title: Method of Enlarging Contact Area of a Gate Electrode, Semiconductor Device Having a Surface-Enlarged Gate Electrode, and Method of Manufacturing the Same

AMENDMENT UNDER 37 C.F.R. §1.111

U.S. Patent and Trademark Office Customer Service Window, Mail Stop Amendment Randolph Building 401 Dulany Street Alexandria, VA 22314

Sir:

In response to the Office Action of June 30, 2005, the period for response to which extends through September 30, 2005, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims begin on page 4 of this paper.

Remarks/Arguments begin on page 11 of this paper.